Evidence for Two G aps and B reakdown of the U em ura P lot in B a_{0.6}K _{0.4}Fe₂A s₂ Single C rystals

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We report a detailed investigation on the lower critical eld H_{c1} of the superconducting $Ba_{0:6}K_{0:4}Fe_{2}As_{2}$ (FeAs-122) single crystals. A pronounced kink is observed on the H_{c1} (T) curve, which is attributed to the existence of two superconducting gaps. By thing the data H_{c1} (T) to the two-gap BCS model in full temperature region, a small gap of $_{a}$ (0) = 2.0 0.3 m eV and a large gap of $_{b}$ (0) = 8:9 0.4 m eV are obtained. The in-plane penetration depth $_{ab}$ (0) is estimated to be 105 nm corresponding to a rather large super uid density, which points to the breakdown of the U em ura plot in FeAs-122 superconductors.

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One of the crucial issues in understanding the superconducting mechanism in recently discovered FeA s-based layered superconductors [1, 2] is the pairing symmetry of the superconducting gap and the nature of the low energy excitations. For LnFeA sO $_{1 \ x}$ F $_{x}$ (FeA s-1111) superconductors with x = 0.040.2 and Ln=La,Ce,Nd,Sm, reports on pairing symmetry are divided into two categories: those favoring a gap with [3, 4, 5, 6, 7] or without [8, 9, 10] nodes. In other aspect, the upper critical eld measurement [11], tunneling spectroscopy [12], NMR [13], magnetic penetration depth measurem ent [14, 15] and M ossbauer [16] experiments indicate the existence of a two-gap nature. However, because m ost of the current experim ents were perform ed on polycrystalline sam ples, the experim ental results within the context of pairing symm etry have not yet reached a consensus.

The emergence of $(Ba_rSr)_{1 \times} K_{\times}Fe_2As_2$ (FeAs-122) [17, 18] hole-doped superconductors with transition tem perature T_c up to 38 K has enriched the research in this area. A lthough stoichiom etric (undoped) BaFe₂As₂ shares the sam e feature with undoped LnFeA so of a spin density wave type magnetic order and a structural transition at sim ilar tem peratures [19, 20], how ever, there are also som e signi cant di erences between the properties of FeA s-1111 and FeA s-122 superconductors. M ost notable is the fact that FeA s-1111 superconductors seem to have very low charge carriers density [2] and hence low super uid density [5, 21]. This may give explanation to the fact that the Uemura plot is satis ed in the FeAs-1111 system s [21, 22]. According to Uem ura et.al. [23], in superconductors with low super uid density ($_{\rm s}$), T $_{\rm c}$ scales linearly with $_{\rm s}$ / $^2_{\rm ab}$ (0), this is actually not required by the BCS theory. However, it is found that the charge carrier density in FeAs-122 is an order of magnitude larger than those in FeAs-1111 systems [17, 24]. Thus it is very interesting to know whether the Uem ura plot is still satis ed in FeA s-122 superconductors.

Lower critical eld H $_{cl}$ (T), or equivalently, m agnetic penetration depth (T) are fundamental probes of the

nature of the pairing sym m etry, or/and multigap of unconventional superconductors. As an advantage, H $_{\rm c1}$ (T) m easurem ent probes relatively large depths (in scale of

100 nm) and are insensitive to sample surface condition. In this Letter we present the rst detailed m agnetic penetration m easurem ents of superconducting $Ba_{0:6}K_{0:4}Fe_2As_2$ single crystals. The local m agnetization m easurem ents allow a precise determ ination of H_{c1} . W e found the presence of possibly a full gap feature together with two gaps in $Ba_{0:6}K_{0:4}Fe_2As_2$ superconductors. M eanwhile, the absolute value of H_{c1} (0) determ ined from this work place the sam ples far away from the U emura plot.

C rystals of $Ba_{0:6}K_{0:4}Fe_2As_2$ were grown by FeAs ux m ethod. The details of crystal synthesis have been described elsewhere [24]. Our crystals were characterized by both resistivity and ac susceptibility measurements with $T_c = 362$ K and a transition width of $T_c = 0.45$ K (10% -90% of norm alstate resistivity) [24], as displayed in left in set of Fig.1 (a). A single crystal (sam ple No. 1) was selected from the cleaved as-grown bulk under opticalm icroscope. The sample has dimensions of 110 m in diameter and 40 m in thickness, as shown in the right inset of Fig. 1 (a). The crystal structure was exam ined by X-ray Diraction (XRD), and a typical diraction pattern was shown in the main panel of Fig. 1(a). Only (001) peaks were observed with the full-width-athalf-maximum (FW HM) around 0.1 , which indicates good crystallization of our sam ples.

The local magnetization measurement was performed on two crystals using a two dimensional electron gas (2DEG)-based micro Hall sensor with an active area of 10 10 m². The Hall sensor was characterized without sample attachment at dierent temperatures, the Hall coe cient R_H was identical to 0.22 /0 e, independent of T below 80 K. In our experiment, we used a small eld sweep rate of 30 0 e/m in to measure the isotherm alm agnetization M (H) curves in both decreasing (M_{dec}) and increasing (M_{inc}) the elds to minimize the complex effects of the character of the eld penetration in a layered



FIG.1: (Color online) (a) X-ray di raction pattern of the $Ba_{0.6}K_{0.4}Fe_2As_2$ crystal. The right inset shows the sample (N o. 1) under the optical microscope. The scale underneath with 100 m/grid is used to display the size of the sam ple. The left inset shows the resistive transition on one crystal cut from the same piece as the one for the measurem ent of H $_{c1}$. (b) The induction B by Hall probe as a function of T measured in zero-eld-cooled mode with applied eld. Inset: A typical magnetization hysteresis loop measured at 32.1 K by the Hall sensor.

structure [25]. A second crystal (sam ple N o. 2) with dimensions of 210 150 50 m³ was also measured by H all sensor and vibrating sam ple magnetom etry (VSM), and both measurem ents showed essentially identical behavior except for the di erent dem agnetization e ect.

In order to check whether the vortex entry is in uenced by the Bean-Levingston surface barrier [26, 27], we measured the magnetization hysteresis loops. The result is shown in the inset of Fig. 1 (b). The M (H) curve shows a symmetric feature at T = 32.1 K which is close to T_c , indicative of the dom inance of bulk pinning and the absence of the Bean-Levingston surface barrier for vortex entry.

The quality of the crystal and the accuracy of the local m agnetization m easurement were demonstrated in Fig. 1 (b), in which the induction B = H + 4 M sensed by the H all probe is plotted as a function of T under a bias eld H = 200 e. The superconducting transition can be detected as the induction jump at $T_c = 35.8 K$ with a width of $T_c = 0.5 K$, which shows the high quality of the crystal. As shown in raw data of B (T), at low tem – peratures, B is close to 0, in plying a full M eissner shielding e ect: 4 M ' H. A Itematively, the magnitude of the change in B m easured by the H all sensor through the superconducting transition is 19.8 0 e, very close to the applied magnetic eld 200 e. Thus the achievement



FIG.2: (Color online) (a) A typical magnetization hysteresis loop (symbols), the solid lines are the linear tting curves using the low eld data (M eissner line). The increasing and decreasing branches are shifted downward and upward, respectively for clarity. The same case is shown in the bottom – left inset when the maximum eld is less than H_{c1}. The upper-right inset shows the magnetization data subtracted the M eissner line. The arrows indicate the direction of sweeping elds and the determ ination of H_{c1}. (b) The initial part of the magnetization curves M (H) of sam ple N o. 2 at various tem peratures. The dashed line gives the M eissner linear approach. Inset: The same magnetization data in eld subtracted by the M eissner line. The dashed line in the inset sets up a criterion of 0.5 O e.

of full M eissner shielding e ect in our measurem ent provides a reliable way to determ ine the value of H $_{c1}$.

Shown in Fig.2 (a) are the typical isotherm al M (H) curves by taking M $_{dec}$ and M $_{inc}$ at T = 17.1 K, respectively. It can be seen that, at low H , the M $_{\rm dec}$ and M $_{\rm in\,c}$ are fully reversible, showing a common linear dependence of the magnetization on eld as displayed in the bottom left inset of Fig. 2(a). At high H, a deviation from the linear dependence occurs at $H = H_{c1}$ for both M_{dec} and M inc curves. To distinguish these deviations, we t more than 50 data points between 10 and 30 O e by a linear relation to account for the common linear dependence of M (H). These tted linear lines describe the M eissner shielding e ects (\M eissner line") at low elds, as evidenced quantitatively in Fig. 2(a) in which the slope of the tted lines are -0.98, being very close to -1. Thus the deviation of M (H) from the linear M eissner shielding is an indication of the rst penetration eld H $_{c1}$. An alternative way to determ ine the value of H $_{c1}$ from these reversible isotherm alM (H) curves is to subtract the M eissner line from both M $_{\rm dec}$ (H) and M $_{\rm inc}$ (H) curves, as illustrated in the upper-right inset of Fig. 2 (a). The threshold eld of non-zero m agnetization happens to be the divergence of the increasing and decreasing M (H) curves. It is noted that the values of H_{c1} with this criterion were determined in both increasing and decreasing eld, so they are the true therm odynamic values and are

not altered by the surface barrier [25].

For a strict treatm ent, we determ ined the value of H $_{c1}$ by exam ining the point of departure from the M eissner line on the initial slope of the M (H) curve. In the inset of Fig. 2 (b) we show how to determ ine H $_{c1}$ by using a criterion of B = M = 0.50 e at di erent temperatures. For a quantum ux $_0 = 20:70 e m^2$, M = 0.50 e is equivalent to about (2 3) $_0$ penetrating into the (10 10) m² sensing area, which is the lim it of our H all probe technique. The H $_{c1}$ values determ ined in this way are about 4% larger than those estim ated from the point where the reversible m agnetization deviates from linearity, and we did not observe any signi cant di erence in the T-dependence of H $_{c1}$ deduced from either of the two criterion.

Shown in Fig. 3(a) and (b) are the main results of our experiment, in which the obtained H $_{\rm cl}$ are plotted as a function of T for crystals N o. 1 and 2, respectively. At T < 4 5 K, H $_{\rm cl}$ (T) is weakly T-dependent and seem s to show a tendency towards saturation at lower T (in the limited temperature range). As illustrated in the insets of Fig. 3(a) and (b), the saturated H $_{\rm cl}$ reach 695 0 e for sam ple N o. 1 and 590 0 e for sam ple N o. 2. This tendency of H $_{\rm cl}$ (T) re ects a possible fully gapped nature of superconducting state at low T for Ba_{0.6}K $_{0.4}$ Fe₂A s₂ superconductors, although we could not rule out the possibility of a sm all gap with nodes in the dirty limit.

A pronounced kink can be easily observed in H_{c1} (T) curves at T 15 K for both samples. O byiously, the occurrence of the kink in H_{c1} (T) can not be explained by the model with an s-wave or d-wave single gap. On the other hand, this kinky structure in H_{c1} (T) resembles that of the related penetration depth of the two-band superconductor M gB₂ [28], in which a positive curvature was observed and explained by the multi-band theory [29]. In addition, recent A R PES measurement resolved a two-gap nature in a sim ilar Ba_{0:6}K_{0:4}Fe₂A s₂ crystal [30, 31]. Thus our observation of a kink in H_{c1} (T) strongly suggests the existence of multiple gaps in Ba_{0:6}K_{0:4}Fe₂A s₂ superconductors, being consistent with that predicted in electronic band structure calculations [32].

Q uantitatively we analyze and discuss in more detail the data of H_{cl}(T) to elucidate the related gap function. For our crystals, assuming _{ab}(0) 100 200 nm [33], the coherence length _{ab}(0) was estimated to be 2-2.5 nm from an extremely high upper critical eld H_{c2} [$_0H_{c2}^{==c}(0) = _0=2 \ _{ab}^2(0)$] [24, 34], and the mean free path (determined from the resistivity at 38 K) is 15 nm, our samples are therefore expected to be in the moderately clean, local limit. In this case the local London m odel is valid to describe the data. For a single gap su-



FIG.3: (C obr online) The extracted H $_{c1}$ as a function of T for sample N o.1 (a) and N o.2 (b) (full circles with error bars). The open dotted circles in (b) represent the H $_{c1}$ determ ined from the V SM m easurements taken into account of the demagnetization e ect. The solid lines are the tting curves using the two-gap m odel [Eq.(1) and Eq.(2)]. The contributions of the small gap [H $_{c1}$ ($_{a}$)] and the large gap [H $_{c1}$ ($_{b}$)] in the m odel are also shown by the dotted and dashed lines, respectively. The two insets in (a) and (b) show the enlarged view s of the data H $_{c1}$ (T) in low tem perature region together with the theoretical tting curves (solid lines) with a two-gap m odel.

perconductor, H _{c1} relates the norm alized super uid density as: e, (T) $^{2}_{ab}(0) = ^{2}_{ab}(T) = H_{c1}(T) = H_{c1}(0)$, and e, (T) is given by [35, 36]

$$e_{\rm s}({\rm T}) = 1 + 2 \int_{0}^{2} \frac{{\rm df}({\rm E})}{{\rm dE}} \frac{{\rm E}}{{\rm E}^{2}} \frac{{\rm E}}{{\rm (T)}^{2}} {\rm dE}$$
 (1)

with f the Fermi function. Here the total energy is $E = \frac{1}{2} + \frac{1}{2}$, and is the single-particle energy measured from the Fermi surface. It is assumed that the gap

on each Ferm i surface follows the weak-coupling BCS tem perature dependence. For a superconductor with two gaps, the norm alized super uid density may be written as

$$e_{s} = x e_{s}^{a} + (1 \ x) e_{s}^{b};$$
 (2)

where x is the fraction of super uid density e_s^a associated with the small gap $_a$. The results of the calculations and H $_{c1}$ of sam pleN o. 1 and 2 are shown by the red solid lines in Fig. 3 (a) and (b), respectively. Fitting the data to above equations (with two s-wave gaps) yields: $_a = 1:6$ 0:3 meV, $_b = 9:1$ 0:3 meV and x= 0.72 for sam pleN o.1, and $_a = 2:2$ 0.2 meV, $_b = 8:8$ 0:3 meV and x= 0.70 for sam pleN o.2. The gaps obtained from our H $_{c1}$ (T) m easurem ents are clearly sm aller than those determ ined from the ARPES m easurem ents[30, 31]. This



FIG. 4: (Color online) The correlations between T_c and the super uid density $n_s = m$. Points for the cuprates are taken from Ref21,22. The full triangles are showing the data for F-LaFeA s0 (Ref5 and Ref21) and F-Sm FeA s0 (Ref13 and our work), both are close to the U em ura plot of the cuprate superconductors. The data of the FeA s-122 phase (the red full circle), M gB₂ and NbSe₂ are far away from the general U em ura plot [23].

discrepancy m ay be induced by the di erent ways and di erent criterions in determ ining the gaps, this should be checked by future experim ents. It is interesting to note that the large gap accounts for only 30% of the total super uid density. W e m ust stress that although a sm all gap with nodes (in the dirty lim it) cannot be excluded from our low temperature data, this will not lead to a signi cant change to the general tting results obtained here.

A nother in portant result of our experim ent, the absolute value of $_{ab}(0)$ is independently deduced from the measured H $_{c1}$ (0). In principle, we evaluate the penetration depth $_{ab}$ (0) using the expression: H $_{c1}^{=-c}$ = $(_{0}=4 \stackrel{2}{_{ab}}) \ln$, where = = is the G inzburg-Landau parameter (here we assume that is T-independent). Using $H_{c1}^{=c}(0) = 695 \text{ Oe and} = 80$, we obtain $_{ab}(0)$ ' 105 nm for sample No. 1 and 115 nm for sample No. 2. The value of $\frac{2}{ab}$ (0), or equivalently the condensed carrier density $n_s = m$ (superconducting carrier density/e ective mass), allows us to check whether the well-known scaling behaviors between $n_s = m$ and T_c still works for the present system. In Fig. 4 we present our results together with many others, including the FeA s-1111 system, cuprates, $M qB_2$ and $N bSe_2$ [37]. It is remarkable that $Ba_{0:6}K_{0:4}Fe_2As_2$ resides far away from the Uem ura plot, which is contrasted by the case of the FeA s-1111 system which is quite close to the U em ura plot. This discrepancy between FeA s-122 and FeA s-1111 in plies very essential di erence between the physics in the two system s, this warrants further investigations.

To summarize, we conduct magnetization measurements on $Ba_{0:6}K_{0:4}Fe_2As_2$ single crystals, and the lower

critical eld H_{c1}(T) is reliably extracted. It is found that H_{c1} exhibits a pronounced kink at T 15 K, which indicates a multi-gap nature. By using the two-gap weak coupling BCS model to t the data, we obtained a small gap of $_{\rm a}$ (0) ' 2:0 0:3 m eV and a large gap of $_{\rm b}$ (0) ' 8:9 0:4 m eV. An estimate of the in-plane penetration depth gives $_{\rm ab}$ (0) ' 105 nm, which points to the breakdown of the U em ura relation for the optim ally doped B $_{\rm a_0:K_0}$: 4Fe₂A s₂ superconductors.

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